



RELIABILITY REPORT  
FOR  
MAX9265GCM/V+T  
PLASTIC ENCAPSULATED DEVICES

November 29, 2011

**MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR.  
SUNNYVALE, CA 94086

<b>Approved by</b>
Richard Aburano
Quality Assurance
Manager, Reliability Engineering

## Conclusion

The MAX9265GCM/V+T successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

## Table of Contents

I. ....Device Description	V. ....Quality Assurance Information
II. ....Manufacturing Information	VI. ....Reliability Evaluation
III. ....Packaging Information	IV. ....Die Information
.....Attachments	

### I. Device Description

#### A. General

The MAX9265 gigabit multimedia serial link (GMSL) serializer features an LVDS system interface and high-bandwidth digital content protection (HDCP) encryption for content protection of DVD and Blu-ray(tm) video and audio data. The serializer pairs with any HDCP GMSL deserializer to form a digital serial link for the transmission of control data and HDCP-encrypted video and audio data. GMSL is an HDCP technology approved by Digital Content Protection (DCP), LLC. The 3-channel mode serializes three lanes of LVDS data (21 bits), UART control signals, and three audio inputs. The 4-channel mode serializes four lanes of LVDS data (28 bits), UART control signals, three audio inputs, and auxiliary control inputs. The three audio inputs are for I<sup>2</sup>S audio, supporting a sampling frequency from 8kHz to 192kHz and a sample depth of 4 to 32 bits. The embedded control channel forms a full-duplex differential 9.6kbps to 1Mbps UART link between the serializer and deserializer. An electronic control unit (ECU), or microcontroller (μC), can be located on the serializer side of the link (typical for video display), on the deserializer side of the link (typical for image sensing), or on both sides. The control channel enables ECU/μC control of peripherals on the remote side, such as backlight control, touch screen, and perform HDCP-related operations. The serial link signaling is AC-coupled CML with 8b/10b coding. For driving longer cables, the serializer has programmable driver pre/deemphasis, and for reduced EMI, has programmable spread spectrum on the serial output. The serial output meets ISO 10605 and IEC 61000-4-2 ESD standards. The serializer operates with a 1.8V core supply, a 1.8V to 3.3V I/O supply, and a 3.3V LVDS supply. This device is available in a 48-pin TQFP package with an exposed pad and is specified over the -40°C to +105°C automotive temperature range.

## II. Manufacturing Information

A. Description/Function:	HDCCP Gigabit Multimedia Serial Link Serializer with LVDS System Interface
B. Process:	0.18 $\mu$ m CMOS
C. Number of Device Transistors:	652852
D. Fabrication Location:	Taiwan
E. Assembly Location:	Korea
F. Date of Initial Production:	December 21, 2010

## III. Packaging Information

A. Package Type:	48-pin TQFP
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (0.8 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-4174
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 3
J. Single Layer Theta Ja:	$^{\circ}$ C/W
K. Single Layer Theta Jc:	$^{\circ}$ C/W
L. Multi Layer Theta Ja:	27.6 $^{\circ}$ C/W
M. Multi Layer Theta Jc:	2 $^{\circ}$ C/W

## IV. Die Information

A. Dimensions:	165.35X163.78 mils
B. Passivation:	Si <sub>3</sub> N <sub>4</sub> /SiO <sub>2</sub> (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu
D. Backside Metallization:	None
E. Minimum Metal Width:	Metal1 = 0.23 / Metal 2-5 = 0.28 / Metal6 = 0.44 micron (as drawn)
F. Minimum Metal Spacing:	Metal1 = 0.23 / Metal 2-5 = 0.28 / Metal6 = 0.46 micron (as drawn)
G. Bondpad Dimensions:	
H. Isolation Dielectric:	SiO <sub>2</sub>
I. Die Separation Method:	Wafer Saw

## V. Quality Assurance Information

A. Quality Assurance Contacts:	Richard Aburano (Manager, Reliability Engineering) Don Lipps (Manager, Reliability Engineering) Bryan Preeshl (Vice President of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
C. Observed Outgoing Defect Rate:	< 50 ppm
D. Sampling Plan:	Mil-Std-105D

## VI. Reliability Evaluation

### A. Accelerated Life Test

The results of the 125°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 2454 \times 250 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 2454 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 7.8 \times 10^{-9}$$

$$\lambda = 7.8 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maxim-ic.com/qa/reliability/monitor>. Cumulative monitor data for the TS18 Process results in a FIT Rate of 0.7 @ 25C and 12.3 @ 55C (0.8 eV, 60% UCL)

### B. E.S.D. and Latch-Up Testing (lots QO5YBQ001C, D/C 1042; QO5YBQ001A, D/C 1113; QO5YAQ001A, D/C 1020)

The HS44-1 die type has been found to have all pins able to withstand a transient pulse of:

ESD-HBM:	+/- 3500V all pins per JEDEC JESD22-A114, +/- 8000V CML/LVDS pins to AGND
ESD-CDM:	+/- 500V per JEDEC JESD22-C101
ESD-MM:	+/- 250V per JEDEC JESD22-A115
ESD gun (contact):	+/- 10kV CML pins per ISO10605, +/- 10kV CML pins per IEC61000-4-2
ESD gun (air gap):	+/- 20kV CML pins per ISO10605, +/- 12kV CML pins per IEC61000-4-2

Latch-Up testing has shown that this device withstands a current of +/- 100mA and overvoltage per JEDEC JESD78.

**Table 1**  
Reliability Evaluation Test Results

**MAX9265GCM/V+T**

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
<b>Static Life Test</b> (Note 1)					
	Ta = 125°C	DC Parameters	92	0	QO5ZBQ001D, D/C 1035
	Biased	& functionality	78	0	QO5ZBQ003B, D/C 1116
	Time = 192 hrs.		80	0	QO5ZBA004A, D/C 1119

Note 1: Life Test Data may represent plastic DIP qualification lots.